

Device Modeling Report

COMPONENTS:

DIODE/ SCHOTTKY RECTIFIER / STANDARD

PART NUMBER: 2FWJ42N

MANUFACTURER: TOSHIBA

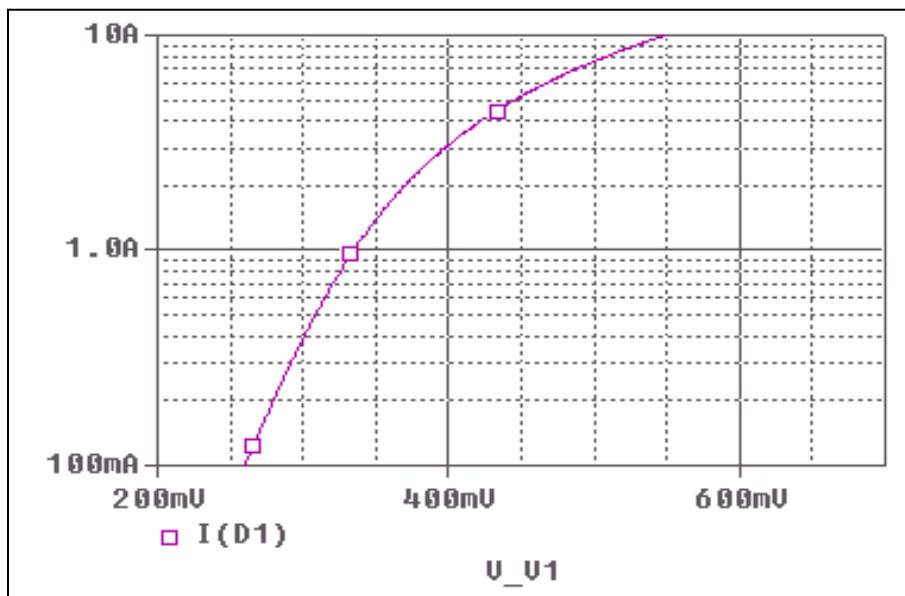


Bee Technologies Inc.

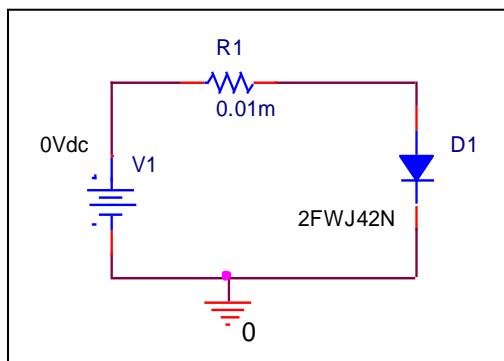
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

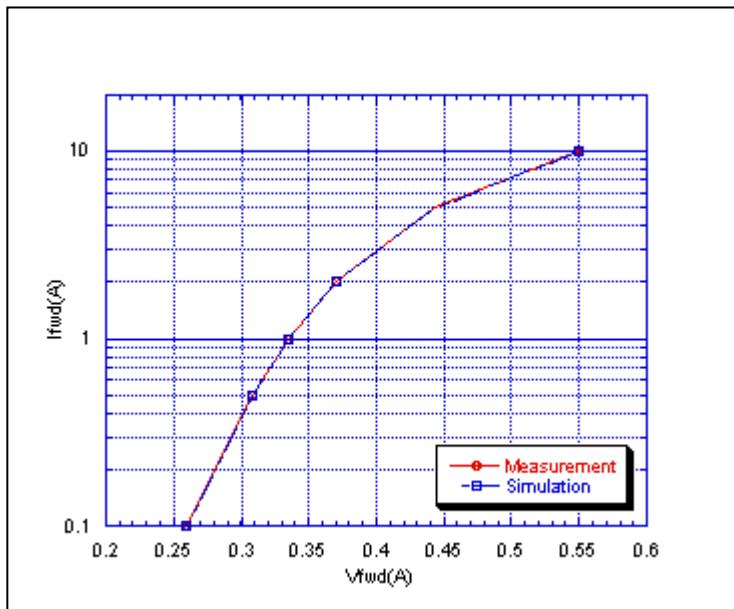


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

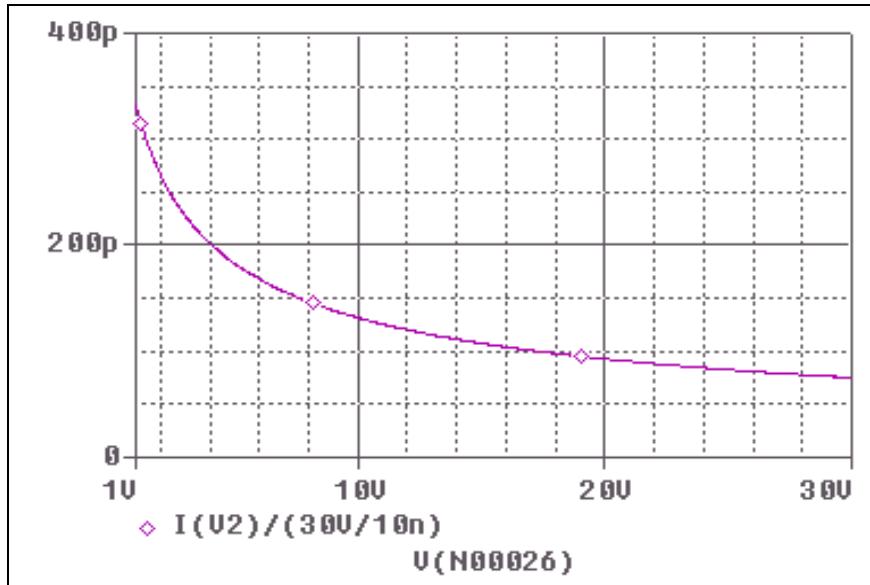


Simulation Result

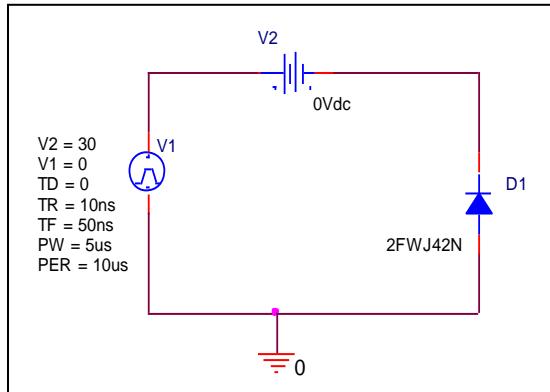
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.1	0.260	0.260	-0.12
0.2	0.280	0.279	-0.25
0.5	0.308	0.308	0.06
1	0.335	0.335	-0.09
2	0.370	0.370	-0.03
5	0.443	0.445	0.47
10	0.550	0.549	-0.16

Junction Capacitance Characteristic

Circuit Simulation Result

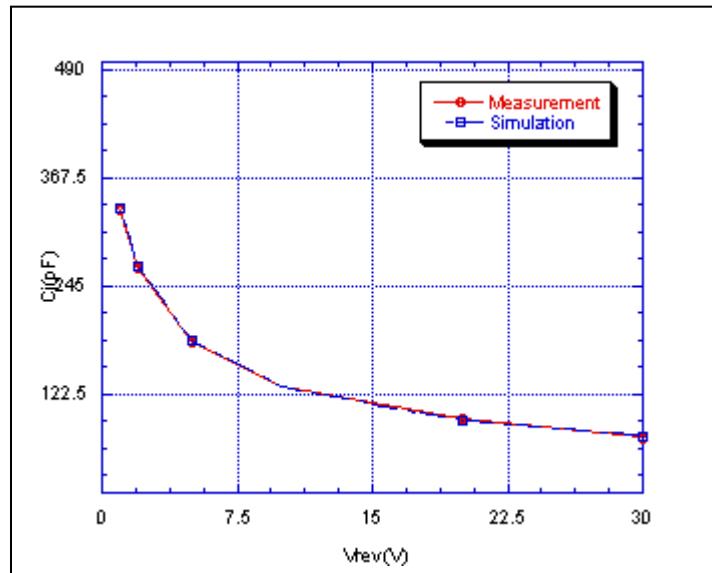


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

$V_{rev}(V)$	$C_j(pF)$ Measurement	$C_j(pF)$ Simulation	%Error
1	330.000	333.100	0.94
2	265.000	266.400	0.53
5	182.000	182.700	0.38
10	132.000	131.600	-0.30
20	95.000	92.800	-2.32
30	73.000	75.100	2.88